Diode Semiconductor Device - Page 1 of 1



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nclosure Mat	erial:
Blass and meta	al
Overall Lengtl	1:
.360 inches	
erminal Leng	th:
.620 inches	
Overall Diame	ter:
.400 inches	
Nounting Met	nod:
erminal	
eatures Prov	ided:
lermetically se	aled case
Semiconducto	or Material:
Silicon	
oltage Rating	g In Volts Per Characteristic:
00.0 reverse	voltage, peak
Current Rating	g Per Characteristic:
0.00 amperes	forward current, average absolute
laximum Ope	erating Tempurature Per Measurement Point:
75.0 degrees	celsius junction
erminal Type	And Quantity:
uninsulated w	<i>i</i> ire lead
Specification	Data:
0131-release2	2365 professional/industrial association specification
Shelf Life:	
l/a	
Jnit Of Measu	re:
-	
Demilitarizatio	n:
10	
iig:	
110a0	